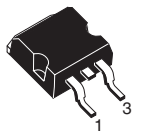
STP200N4F3
STB200N4F3

N-channel 40 V, 0.0025 Ω, 120 A, D²PAK, TO-220 planar STripFET™ Power MOSFET

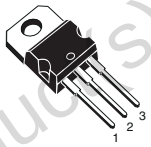
Features

Type	V_{DSS}	$R_{DS(on)}$ max	I_D	P_w
STB200N4F3	40 V	<0.0031 Ω	120 A	300 W
STP200N4F3	40 V	<0.0035 Ω	120 A	300 W

- 100 % avalanche tested
- Standard threshold drive



D²PAK



TO-220

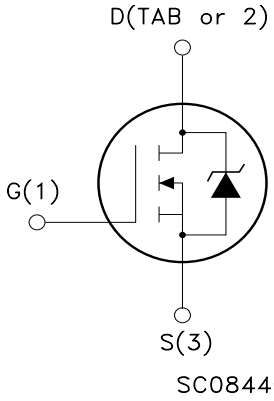
Application

- Switching applications
- Automotive

Description

This STripFET™ III Power MOSFET technology is among the latest improvements, which have been especially tailored to minimize on-state resistance providing superior switching performances.

Figure 1. Internal schematic diagram



Obsolete Product(s) - Obsolete Product(s)

Table 1. Device summary

Order code	Marking	Package	Packaging
STB200N4F3	200N4F3	D²PAK	Tape and reel
STP200N4F3	200N4F3	TO-220	Tube

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2 Electrical characteristics 4

2.1 Electrical characteristics (curves) 6

3 Test circuits 8

4 Package mechanical data 9

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6 Revision history 13

Obsolete Product(s) - Obsolete Product(s)

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V_{DS}	Drain-source voltage	40	V
V_{GS}	Gate-source voltage	±20	V
I_D (1)	Drain current (continuous) at T_C = 25 °C	120	A
I_D (1)	Drain current (continuous) at T_C = 100 °C	120	A
I_{DM} (2)	Drain current (pulsed)	480	A
P_{TOT}	Total dissipation at T_C = 25 °C	300	W
	Derating factor	2.0	W/°C
E_{AS} (3)	Single pulse avalanche energy	862	mJ
dv/dt(4)	Peak diode recovery voltage slope	4.2	V/ns
T_J T_{stg}	Operating junction temperature Storage temperature	-55 to 175	°C

1. Current limited by package
2. Pulse width limited by safe operating area
3. Starting Tj = 25°C, I_D = 60A, V_{DD}= 25V
4. I_{SD} ≤60A, di/dt ≤440 A/µs, V_{DD} ≤$V_{(BR)DSS}$, T_j ≤T_{JMAX}.

Table 3. Thermal data

Symbol	Parameter	Value		Unit
		TO-220	D²PAK	
R_{thJC}	Thermal resistance junction-case max	0.50		°C/W
$R_{thJ\text{-}PCB}$ (1)	Thermal resistance junction-pcb max		35	°C/W
R_{thJA}	Thermal resistance junction-ambient max	62.5		°C/W

1. When mounted on FR-4 board, 1inch² 2 oz. Cu.

Obsolete Product(s) Obsolete Product(s)

2 Electrical characteristics

(T_{CASE} = 25 °C unless otherwise specified)

Table 4. On/off states

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$V_{(BR)DSS}$	Drain-source breakdown voltage	I_D = 250 µA, V_{GS} = 0	40			V
I_{DSS}	Zero gate voltage drain current (V_{GS} = 0)	V_{DS} = Max rating, V_{DS} = Max rating @125 °C			10 100	µA µA
I_{GSS}	Gate body leakage current (V_{DS} = 0)	V_{GS} = ± 20 V			±100	nA
$V_{GS(th)}$	Gate threshold voltage	V_{DS} = V_{GS}, I_D = 250 µA	2		4	V
$R_{DS(on)}$	Static drain-source on resistance	V_{GS} = 10 V, I_D= 60 A D²PAK TO-220		 0.0025 0.0030	 0.0031 0.0035	 Ω Ω

Table 5. Dynamic

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
g_{fs} (1)	Forward transconductance	V_{DS} = 10 V, I_D = 80 A	-	200	-	S
C_{iss} C_{oss} C_{rss}	Input capacitance Output capacitance Reverse transfer capacitance	V_{DS} = 25 V, f = 1 MHz, V_{GS} = 0	-	5100 1270 37	-	pF pF pF
Q_g Q_{gs} Q_{gd}	Total gate charge Gate-source charge Gate-drain charge	V_{DD} = 20 V, I_D = 120 A V_{GS} = 10 V *(see Figure 14)*	-	75 23 17	-	nC nC nC

1. Pulsed: pulse duration=300µs, duty cycle 1.5%

Obsolete Product(s) - Obsolete Product(s)

Table 6. Switching times

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
$t_{d(on)}$ t_r	Turn-on delay time Rise time	V_{DD} = 20 V, I_D = 60 A, R_G = 4.7 Ω, V_{GS} = 10 V *(see Figure 13)*	-	19 180	-	ns ns
$t_{d(off)}$ t_f	Off-voltage rise time Fall time	V_{DD} = 20 V, I_D = 60 A, R_G = 4.7 Ω, V_{GS} = 10 V *(see Figure 13)*	-	90 65	-	ns ns

Table 7. Source drain diode

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit
I_{SD} I_{SDM}	Source-drain current Source-drain current (pulsed)		-		120 480	A A
V_{SD}	Forward on voltage	I_{SD} = 120 A, V_{GS} = 0	-		1.5	V
t_{rr} Q_{rr} I_{RRM}	Reverse recovery time Reverse recovery charge Reverse recovery current	I_{SD} = 120 A, di/dt = 100 A/µs, V_{DD} = 20 V, T_J = 150 °C *(see Figure 18)*	-	67 130 4		ns nC A

Obsolete Product(s) - Obsolete Product(s)

2.1 Electrical characteristics (curves)

Figure 2. Safe operating area

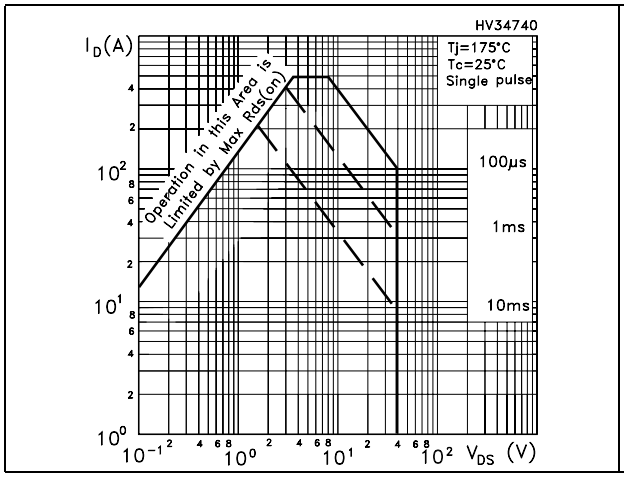


Figure 3. Thermal impedance

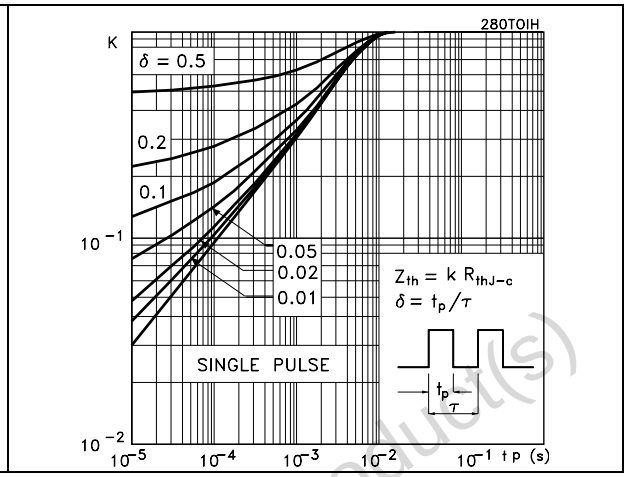


Figure 4. Output characteristics

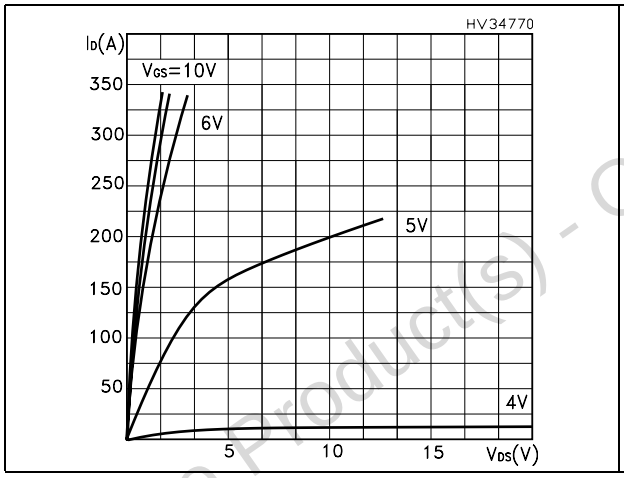


Figure 5. Transfer characteristics

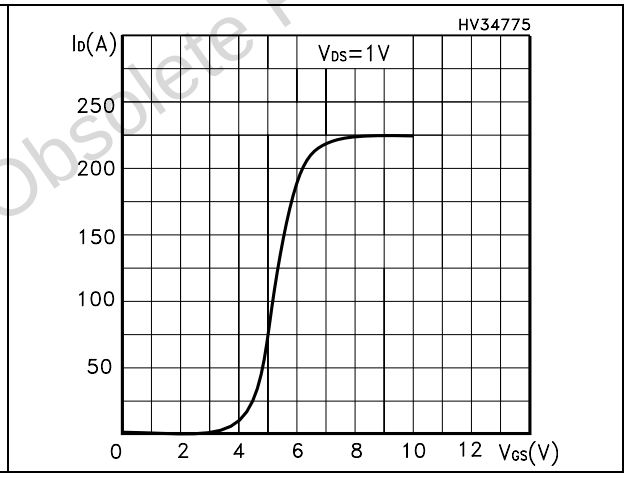


Figure 6. Normalized B_{VDSS} vs. temperature

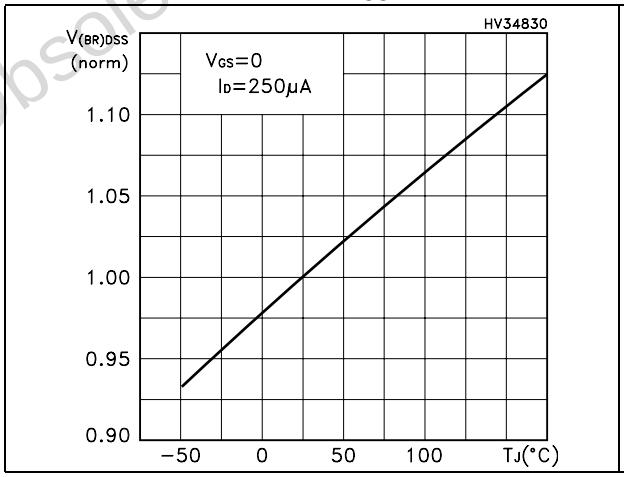
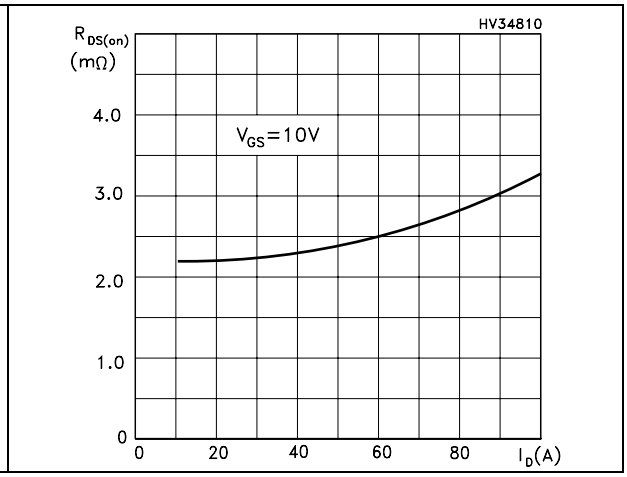


Figure 7. Static drain-source on resistance



Obsolete Product(s) - Obsolete Product(s)

Figure 8. Gate charge vs. gate-source voltage

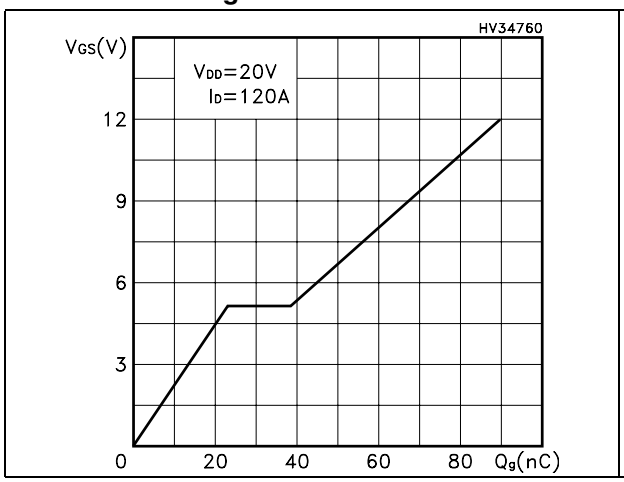


Figure 9. Capacitance variations

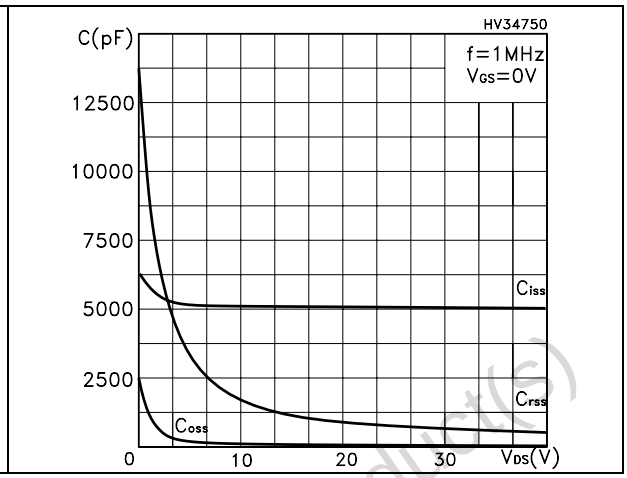


Figure 10. Normalized gate threshold voltage vs. temperature

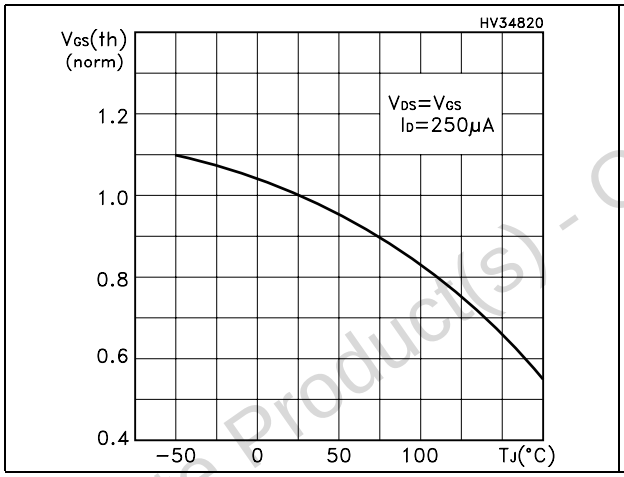


Figure 11. Normalized on resistance vs. temperature

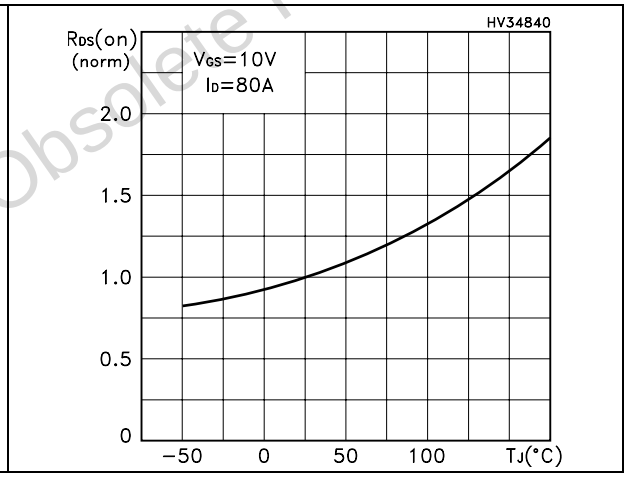
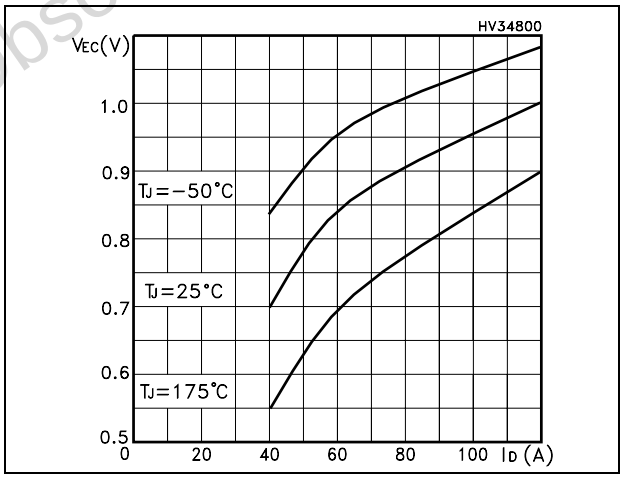


Figure 12. Source-drain diode forward characteristics



Obsolete Product(s) - Obsolete Product(s)

3 Test circuits

Figure 13. Switching times test circuit for resistive load

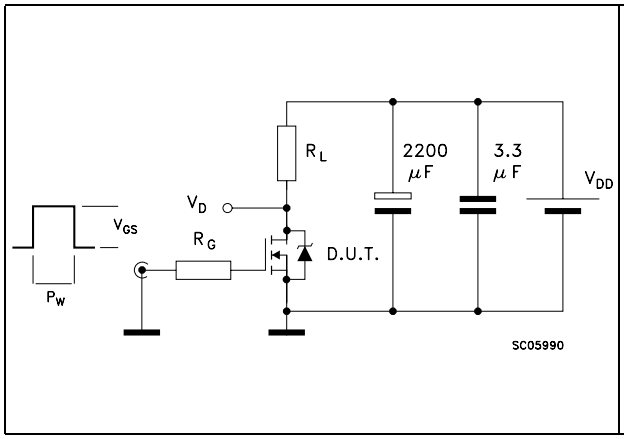


Figure 14. Gate charge test circuit

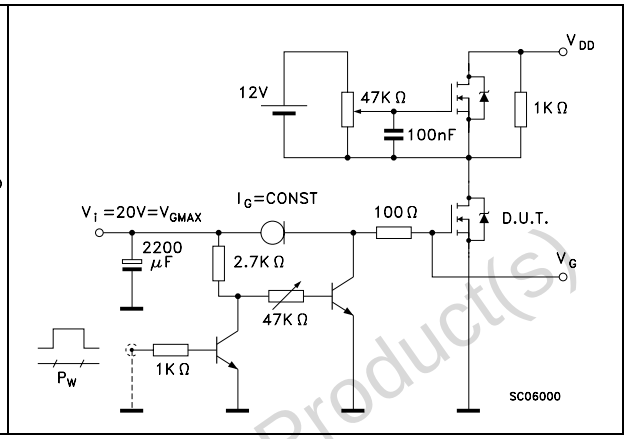


Figure 15. Test circuit for inductive load switching and diode recovery times

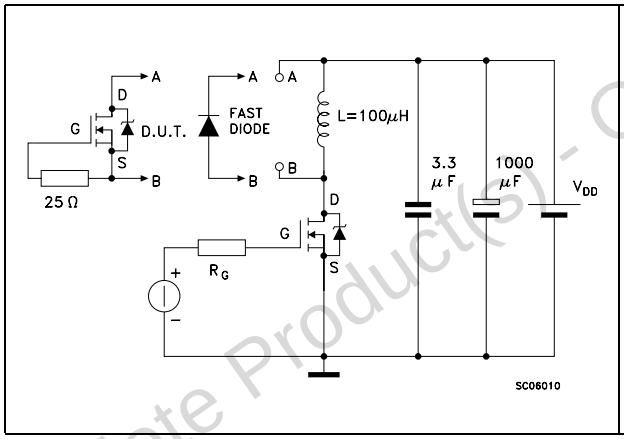


Figure 16. Unclamped inductive load test circuit

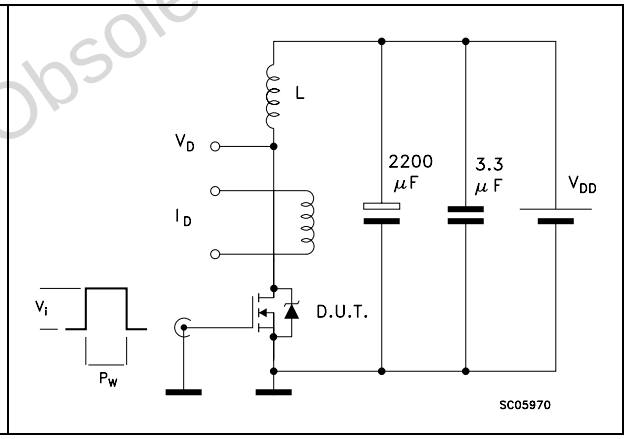


Figure 17. Unclamped inductive waveform

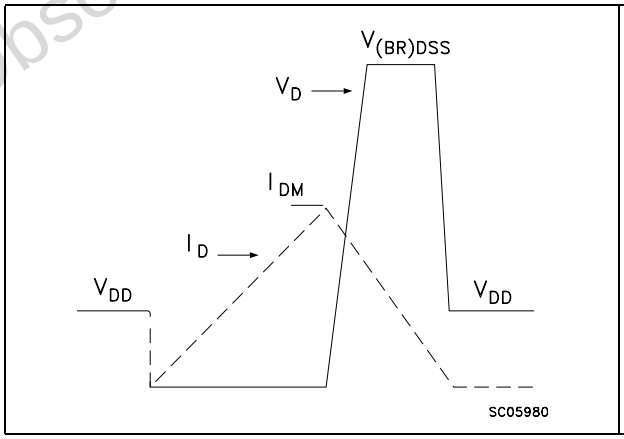
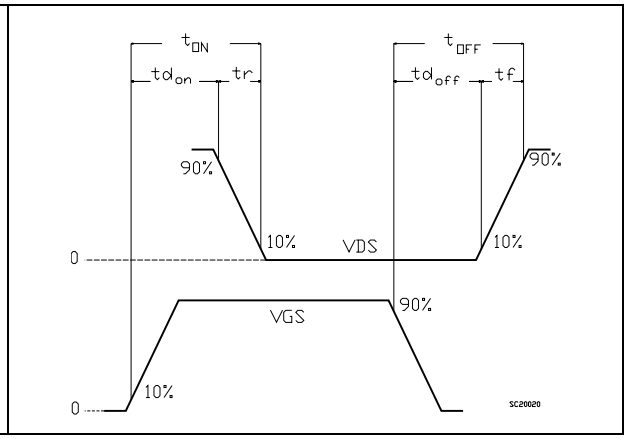


Figure 18. Switching time waveform



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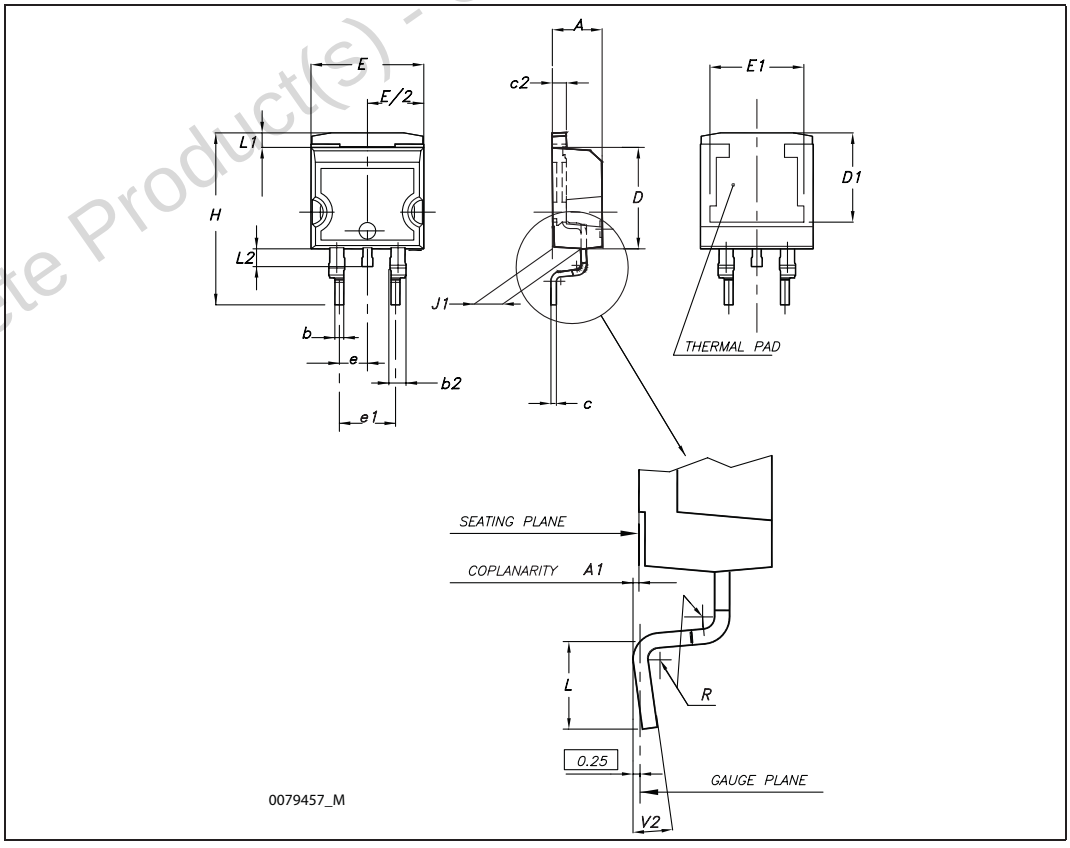
4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: *www.st.com*. ECOPACK® is an ST trademark.

Obsolete Product(s) - Obsolete Product(s)

D²PAK (TO-263) mechanical data

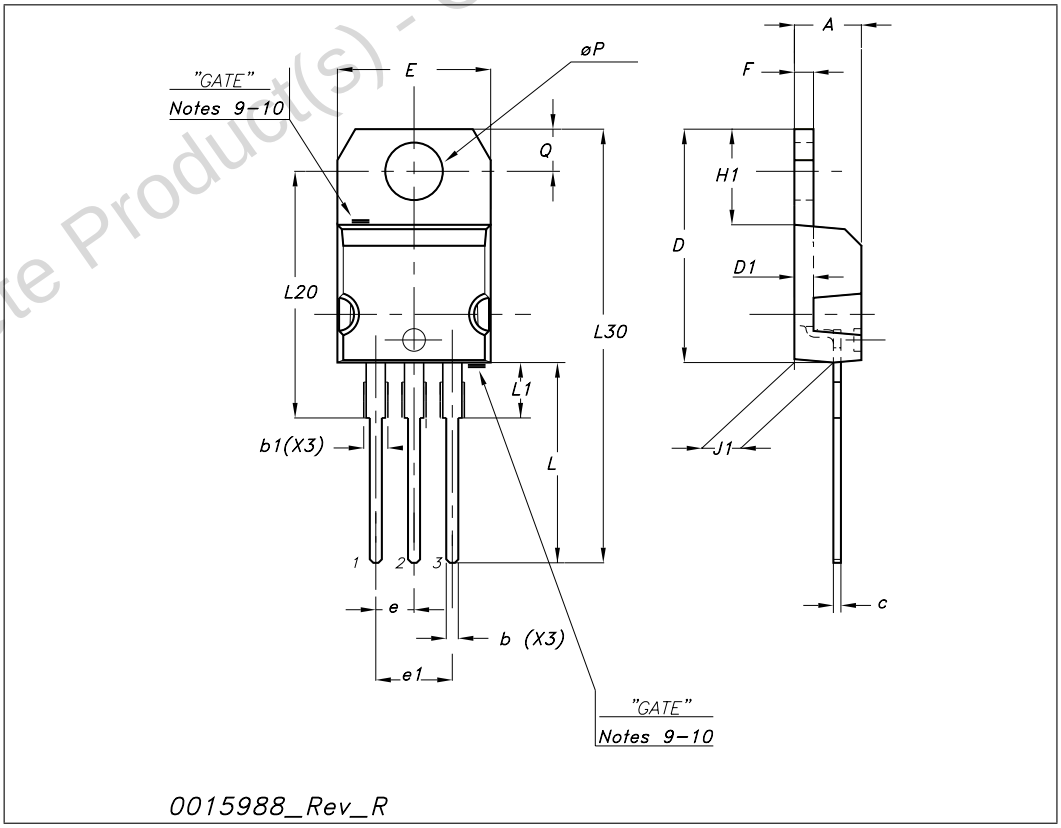
Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.027		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.017		0.024
c2	1.23		1.36	0.048		0.053
D	8.95		9.35	0.352		0.368
D1	7.50			0.295		
E	10		10.40	0.394		0.409
E1	8.50			0.334		
e		2.54			0.1	
e1	4.88		5.28	0.192		0.208
H	15		15.85	0.590		0.624
J1	2.49		2.69	0.099		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°



Obsolete Product(s) - Obsolete Product(s)

TO-220 mechanical data

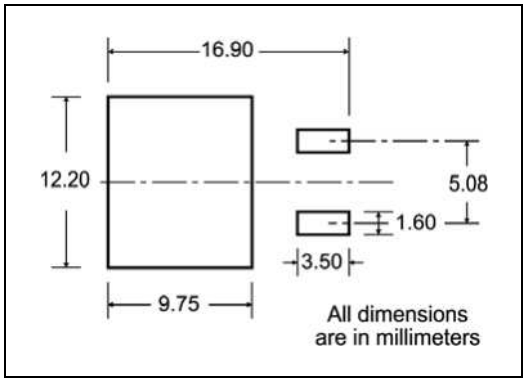
Dim	mm			inch		
	Min	Typ	Max	Min	Typ	Max
A	4.40		4.60	0.173		0.181
b	0.61		0.88	0.024		0.034
b1	1.14		1.70	0.044		0.066
c	0.48		0.70	0.019		0.027
D	15.25		15.75	0.6		0.62
D1		1.27			0.050	
E	10		10.40	0.393		0.409
e	2.40		2.70	0.094		0.106
e1	4.95		5.15	0.194		0.202
F	1.23		1.32	0.048		0.051
H1	6.20		6.60	0.244		0.256
J1	2.40		2.72	0.094		0.107
L	13		14	0.511		0.551
L1	3.50		3.93	0.137		0.154
L20		16.40			0.645	
L30		28.90			1.137	
∅P	3.75		3.85	0.147		0.151
Q	2.65		2.95	0.104		0.116



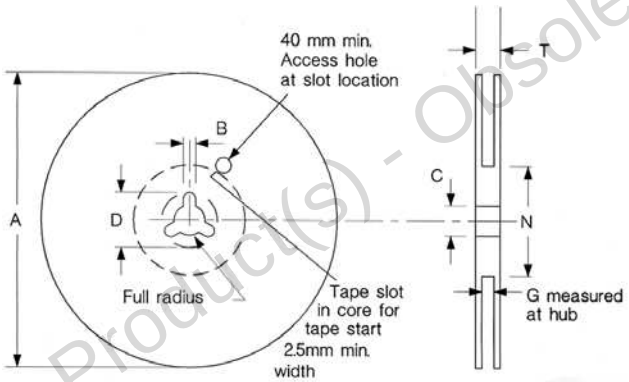
Obsolete Product(s) - Obsolete Product(s)

5 Packaging mechanical data

D²PAK FOOTPRINT



TAPE AND REEL SHIPMENT



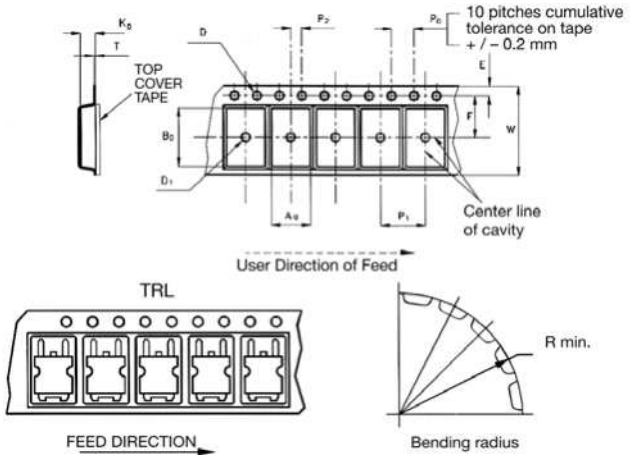
REEL MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A		330		12.992
B	1.5		0.059	
C	12.8	13.2	0.504	0.520
D	20.2		0795	
G	24.4	26.4	0.960	1.039
N	100		3.937	
T		30.4		1.197

BASE QTY	BULK QTY
1000	1000

TAPE MECHANICAL DATA

DIM.	mm		inch	
	MIN.	MAX.	MIN.	MAX.
A0	10.5	10.7	0.413	0.421
B0	15.7	15.9	0.618	0.626
D	1.5	1.6	0.059	0.063
D1	1.59	1.61	0.062	0.063
E	1.65	1.85	0.065	0.073
F	11.4	11.6	0.449	0.456
K0	4.8	5.0	0.189	0.197
P0	3.9	4.1	0.153	0.161
P1	11.9	12.1	0.468	0.476
P2	1.9	2.1	0.075	0.082
R	50		1.574	
T	0.25	0.35	0.0098	0.0137
W	23.7	24.3	0.933	0.956



* on sales type

Obsolete Product(s) - Obsolete Product(s)

6 Revision history

Table 8. Document revision history

Date	Revision	Changes
02-Mar-2007	1	First release
02-Oct-2007	2	Added TO-220 package
23-Jun-2009	3	Updated $R_{DS(on)}$ limits in *Table 4* and *Figure 7*

Obsolete Product(s) - Obsolete Product(s)

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